

• Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



## **NPN Epitaxial Silicon Transistor**

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	35	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
V <sub>EBO</sub>	Emitter-Base Voltage	4	V
С	Collector Current	30	mA
Pc	Collector Power Dissipation	250	mW
ТJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

## Absolute Maximum Ratings $T_a=25^{\circ}C$ unless otherwise noted

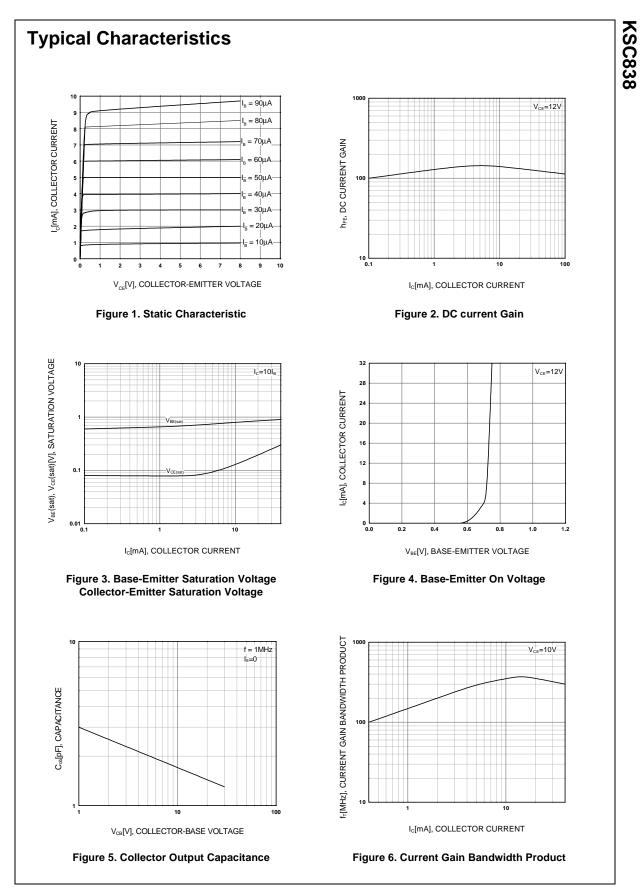
### Electrical Characteristics T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> =100μA, I <sub>E</sub> =0	35			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> =5mA, I <sub>B</sub> =0	30			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> =10μA, I <sub>C</sub> =0	4			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =30V, I <sub>E</sub> =0			0.1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> =4V, I <sub>C</sub> =0			0.1	μΑ
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =12V, I <sub>C</sub> =2mA	40		240	
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =6V, I <sub>C</sub> =1mA	0.65	0.70	0.75	V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =1mA		0.1	0.4	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =10V, I <sub>C</sub> =1mA	100	250		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		2.0	3.2	pF

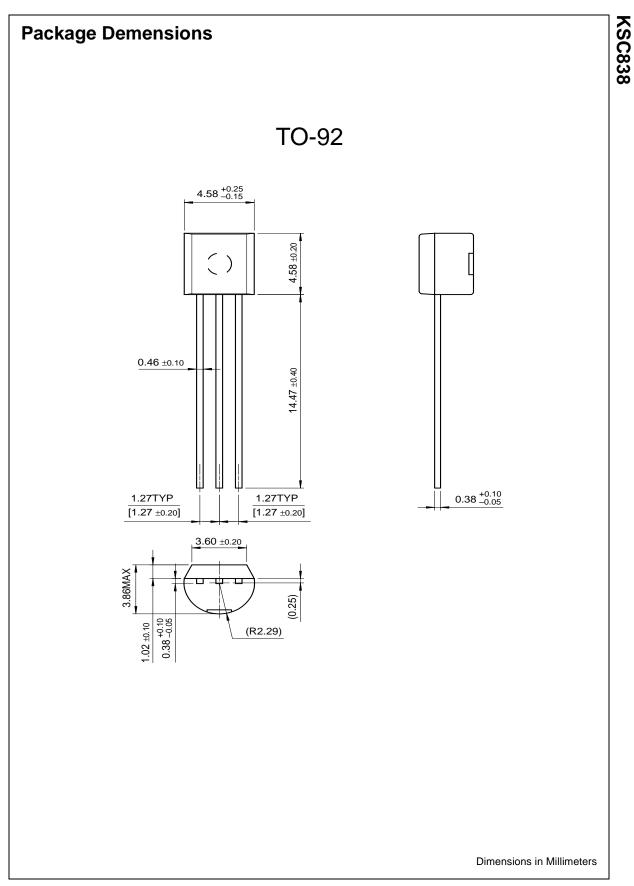
## h<sub>FE</sub> Classification

Classification	R	0	Y
h <sub>FE</sub>	40 ~ 80	70 ~ 140	120 ~ 240

# **KSC**838



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